


MKP1V120 Series

Sidac High Voltage

Bidirectional Triggers

Bidirectional devices designed for direct interface with the ac power line. Upon reaching the breakover voltage in each direction, the device switches from a blocking state to a low voltage on-state. Conduction will continue like a Triac until the main terminal current drops below the holding current. The plastic axial lead package provides high pulse current capability at low cost. Glass passivation insures reliable operation.

Features

- High Pressure Sodium Vapor Lighting
- Strobes and Flashers
- Igniters
- High Voltage Regulators
- Pulse Generators
- Used to Trigger Gates of SCR's and Triacs
-  Indicates UL Registered – File #E210057
- These are Pb-Free Devices*

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Sine Wave, 50 to 60 Hz, T _J = -40 to 125°C) MKP1V120, MKP1V130, MKP1V160 MKP1V240	V _{DRM} , V _{RRM}	± 90 ± 180	V
On-State Current RMS (T _L = 80°C, Lead Length = 3/8", All Conduction Angles)	I _{T(RMS)}	± 0.9	A
Peak Non-repetitive Surge Current (60 Hz One Cycle Sine Wave, T _J = 125°C)	I _{TSM}	± 4.0	A
Operating Junction Temperature Range	T _J	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Lead Lead Length = 3/8"	R _{θJL}	40	°C/W
Lead Solder Temperature (Lead Length ≥ 1/16" from Case, 10 s Max)	T _L	260	°C


Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

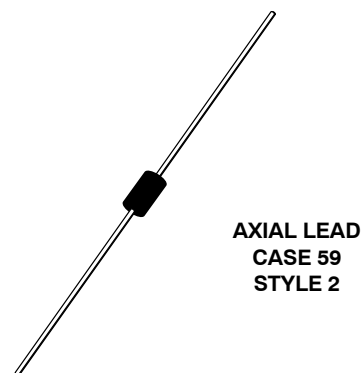
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



ON Semiconductor®

<http://onsemi.com>

SIDACS 
0.9 AMPERES RMS
120 – 240 VOLTS



**AXIAL LEAD
CASE 59
STYLE 2**

MARKING DIAGRAM



A = Assembly Location
 MKP1Vxx0 = Device Number
 x = 12, 13, 16 or 24
 YY = Year
 WW = Work Week
 ■ = Pb-Free Package
 (Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

MKP1V120 Series

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
----------------	--------	-----	-----	-----	------

OFF CHARACTERISTICS

Repetitive Peak Off-State Current T _J = 25°C (50 to 60 Hz Sine Wave) V _{DRM} = 90 V, MKP1V120, MKP1V130 and MKP1V160 V _{DRM} = 180 V, MKP1V240	I _{DRM}	-	-	5.0	μA
--	------------------	---	---	-----	----

ON CHARACTERISTICS

Breakover Voltage I _{BO} = 35 μA MKP1V120 35 μA MKP1V130 200 μA MKP1V160 35 μA MKP1V240	V _{BO}	110 120 150 220	- - - -	130 140 170 250	V
Peak On-State Voltage (I _{TM} = 1 A Peak, Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%)	V _{TM}	-	1.3	1.5	V
Dynamic Holding Current (Sine Wave, 50 to 60 Hz, R _L = 100 Ohm)	I _H	-	-	100	mA
Switching Resistance (Sine Wave, 50 to 60 Hz)	R _S	0.1	-	-	kΩ

DYNAMIC CHARACTERISTICS

Critical Rate-of-Rise of On-State Current, Critical Damped Waveform Circuit (I _{PK} = 130 Amps, Pulse Width = 10 μsec)	di/dt	-	120	-	A/μs
---	-------	---	-----	---	------

ORDERING INFORMATION

Device	Package*	Shipping†
MKP1V120RLG	DO-41, Axial Lead	5000 / Tape & Reel
MKP1V130RLG		5000 / Tape & Reel
MKP1V160G		1000 Units / Bulk
MKP1V160RLG		5000 / Tape & Reel
MKP1V240G		1000 Units / Bulk
MKP1V240RLG		5000 / Tape & Reel

*This package is inherently Pb-Free.

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MKP1V120 Series

Voltage Current Characteristic of SIDAC (Bidirectional Device)

Symbol	Parameter
I_{DRM}	Off State Leakage Current
V_{DRM}	Off State Repetitive Blocking Voltage
V_{BO}	Breakover Voltage
I_{BO}	Breakover Current
I_H	Holding Current
V_{TM}	On State Voltage
I_{TM}	Peak on State Current

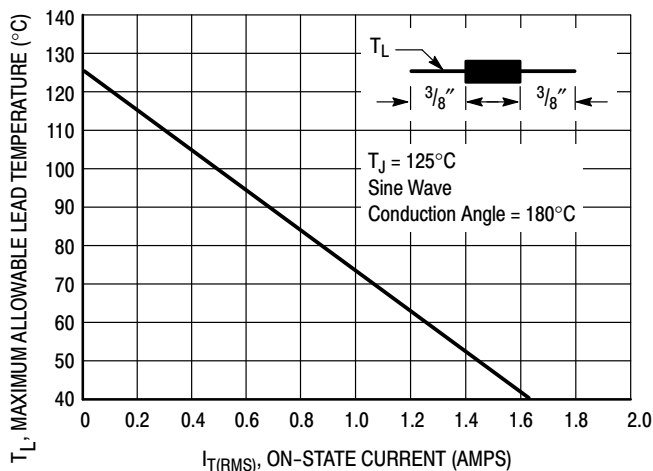
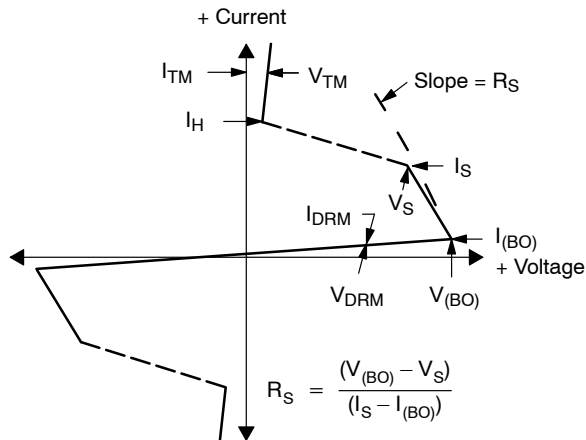


Figure 1. Maximum Lead Temperature

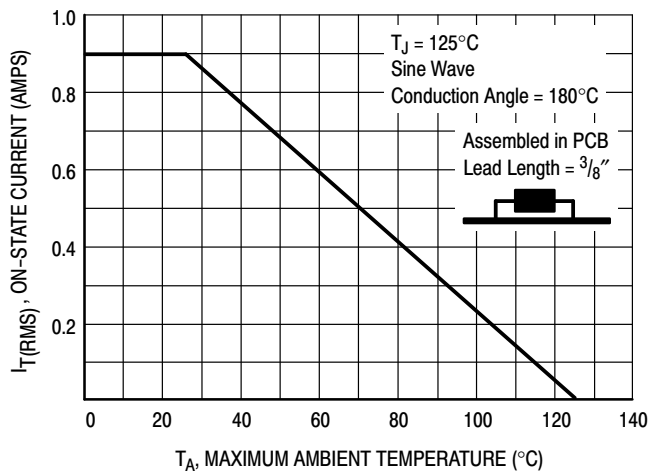


Figure 2. Maximum Ambient Temperature

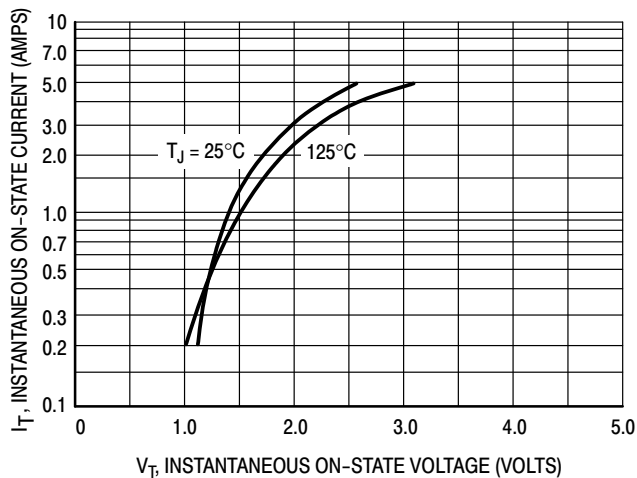


Figure 3. Typical On-State Voltage

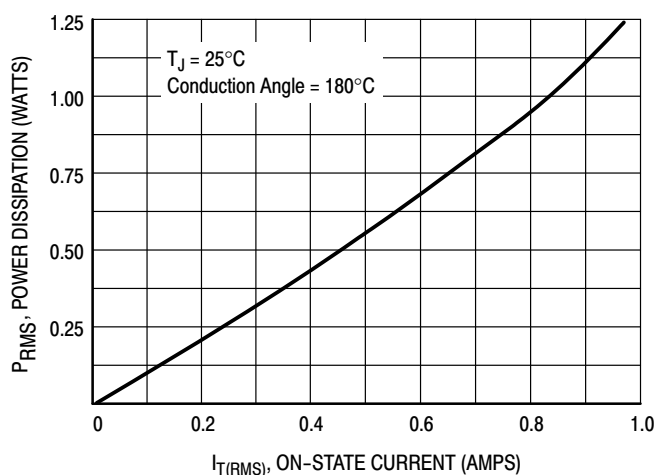


Figure 4. Typical Power Dissipation

MKP1V120 Series

THERMAL CHARACTERISTICS

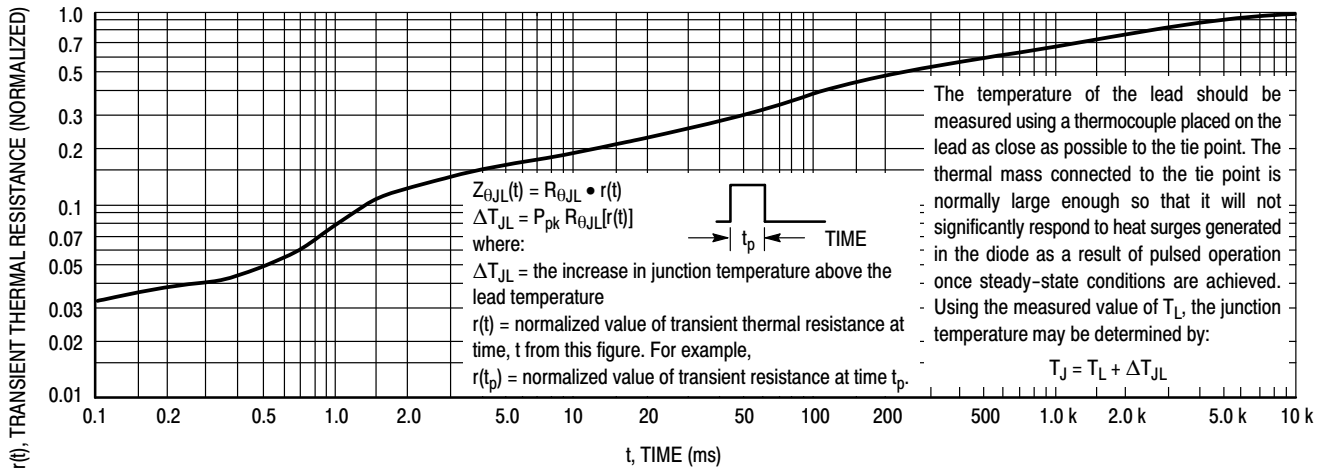


Figure 5. Thermal Response

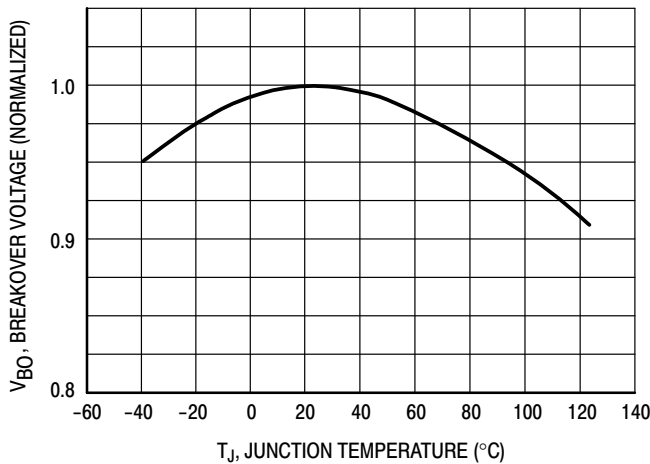


Figure 6. Typical Breakover Voltage

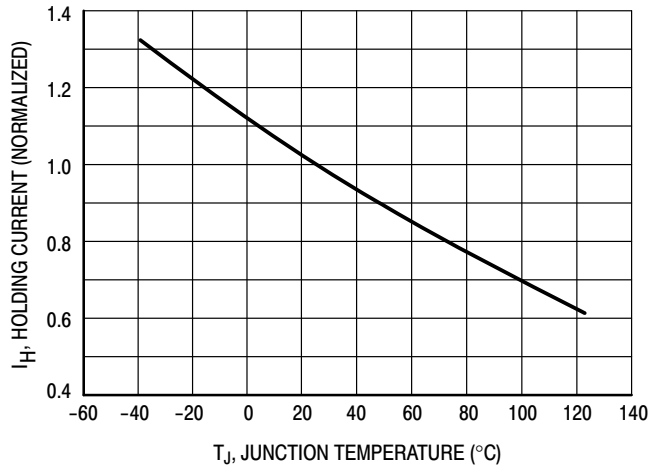


Figure 7. Typical Holding Current

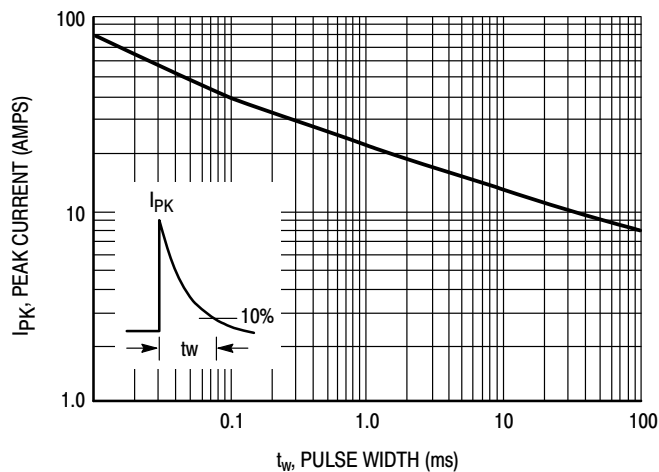
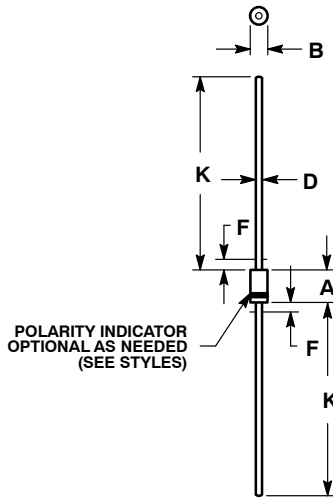


Figure 8. Pulse Rating Curve

MKP1V120 Series

PACKAGE DIMENSIONS

AXIAL LEAD CASE 59-10 ISSUE U



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH JEDEC DO-41 OUTLINE SHALL APPLY
4. POLARITY DENOTED BY CATHODE BAND.
5. LEAD DIAMETER NOT CONTROLLED WITHIN F DIMENSION.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.161	0.205	4.10	5.20
B	0.079	0.106	2.00	2.70
D	0.028	0.034	0.71	0.86
F	---	0.050	---	1.27
K	1.000	---	25.40	---

STYLE 2:
NO POLARITY

ON Semiconductor and **ON** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative